NSN 5962-01-165-5443

Memory Microcircuit - Page 1 of 2



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De du Len ath	
Body Length:	
0.840 inches	
Body Width:	
Between 0.220 inches and	0.310 inches
Body Height:	
Between 0.140 inches and	
Maximum Power Dissipat	ion Rating:
739.0 milliwatts	
Operating Tempurature R	
-55.0/+125.0 degrees celsi	
Storage Tempurature Rar	
-65.0/+150.0 degrees celsiu	SL
Features Provided:	
	onolithic and programmable and schottky and 3-state output
Inclosure Material:	
Ceramic and glass	
Inclosure Configuration:	
Dual-in-line	
Output Logic Form:	
Transistor-transistor logic	
Input Circuit Pattern:	
6 input	
Case Outline Source And	Designator:
D-2 mil-m-38510	
Terminal Surface Treatme	ent:
Solder	
Voltage Rating And Type	Per Characteristic:
5.5 volts power source	
Time Rating Per Chacteris	
	gation delay time, low to high level output and 80.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Type:	
Rom	
Memory Capacity:	
Unknown	
Terminal Type And Quant	tity:
16 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
Yes - demil/mli	

NSN 5962-01-165-5443

Memory Microcircuit - Page 2 of 2

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